

Excellent Integrated System Limited

Stocking Distributor

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<u>Vishay Semiconductor/Diodes Division</u> <u>V20120SHM3/4W</u>

For any questions, you can email us directly: sales@integrated-circuit.com

Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of V20120SHM3/4W - DIODE SCHOTTKY 20A 120V TO-220AB

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V20120S, VI20120S

COMPLIANT

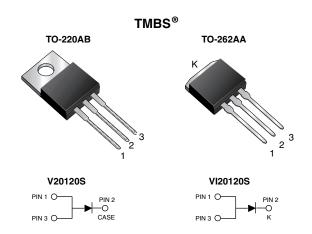
HALOGEN

FREE

Vishay General Semiconductor

High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.50 \text{ V}$ at $I_F = 5 \text{ A}$



PRIMARY CHARACTERISTICS				
I _{F(AV)}	20 A			
V_{RRM}	120 V			
I _{FSM}	200 A			
V_F at $I_F = 20 A$	0.73 V			
T _J max.	150 °C			
Package	TO-220AB, TO-262AA			
Diode variation Single die				

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation
- Solder bath temperature 275 °C max. 10 s, per JESD 22-B106
- AEC-Q101 qualified
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant,

commercial grade

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix

meets JESD class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	V20120S	VI20120S	UNIT	
Maximum repetitive peak reverse voltage	V_{RRM}	120		V	
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	20		Α	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	200		А	
Voltage rate of change (rated V _R)	dV/dt	10 000		V/µs	
Operating junction and storage temperature range	T _J , T _{STG}	-40 to +150		°C	

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.57	-	V
	I _F = 10 A			0.71	-	
	I _F = 20 A			0.99	1.12	
	I _F = 5 A	T _A = 125 °C		0.50	-	
	I _F = 10 A			0.61	-	
	I _F = 20 A			0.73	0.81	
Reverse current	V _R = 90 V	T _A = 25 °C	I _R (2)	10	-	μA
	V _R = 90 V	T _A = 125 °C		6	-	mA
	V _R = 120 V	T _A = 25 °C		-	300	μΑ
	v _R = 120 v	T _A = 125 °C		14	30	mA

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	V20120S	VI20120S	UNIT	
Typical thermal resistance	$R_{ heta JC}$	2.0		°C/W	

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	V20120S-M3/4W	1.88	4W	50/tube	Tube
TO-262AA	VI20120S-M3/4W	1.45	4W	50/tube	Tube
TO-220AB	V20120SHM3/4W (1)	1.88	4W	50/tube	Tube
TO-262AA	VI20120SHM3/4W (1)	1.45	4W	50/tube	Tube

Note

(1) AEC-Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

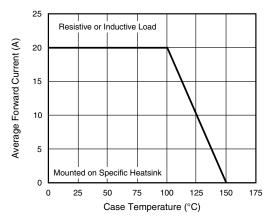


Fig. 1 - Maximum Forward Current Derating Curve

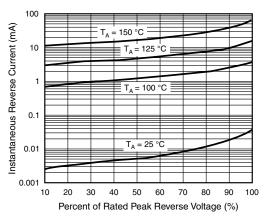


Fig. 4 - Typical Reverse Characteristics

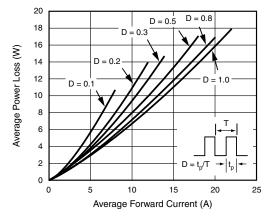


Fig. 2 - Forward Power Dissipation Characteristics

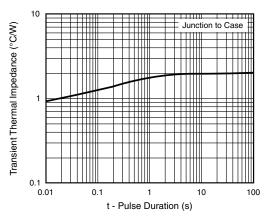


Fig. 5 - Typical Transient Thermal Impedance

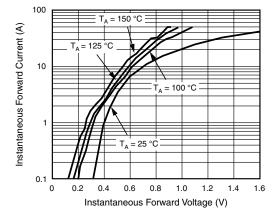


Fig. 3 - Typical Instantaneous Forward Characteristics

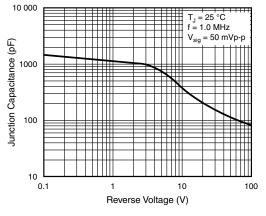


Fig. 6 - Typical Junction Capacitance

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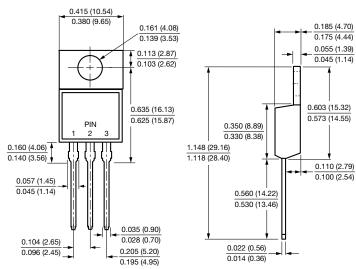


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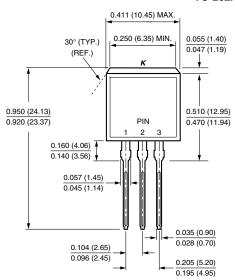
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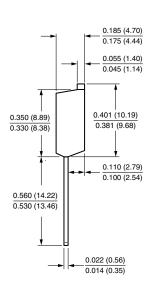
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB



TO-262AA







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